



HFZT

SCS210KE2HR

## SiC Schottky Barrier Diode

VOLTAGE RANGE: 1200V

## Features

- Shorter recovery time
- Reduced temperature dependence
- High-speed switching possible

## MECHANICAL DATA

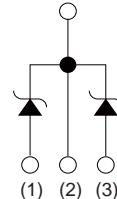
- Case style: TO-247 molded plastic
- Mounting position: any

## ● AEC-Q101 Qualified

TO-247



## ● Inner circuit



(1) Anode  
(2) Cathode  
(3) Anode

## MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Value	Unit
Reverse voltage (repetitive peak)	V <sub>RM</sub>	1200	V
Reverse voltage (DC)	V <sub>R</sub>	1200	V
Continuous forward current <sup>7</sup>	I <sub>F</sub>	5/10 <sup>*1</sup>	A
		23/46 <sup>*2</sup>	A
Surge no repetitive forward current <sup>7</sup>	I <sub>FSM</sub>	87/170 <sup>*3</sup>	A
		18/36 <sup>*4</sup>	A
Repetitive peak forward current <sup>7</sup>	I <sub>FRM</sub>	24/49 <sup>*5</sup>	A
Total power dissipation <sup>7</sup>	P <sub>D</sub>	80/170 <sup>*6</sup>	W
Junction temperature	T <sub>j</sub>	175	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +175	°C

\*1 T<sub>c</sub>=148°C/T<sub>c</sub>=150°C \*2 PW=8.3ms sinusoidal, T<sub>j</sub>=25°C \*3 PW=10μs square, T<sub>j</sub>=25°C\*4 PW=8.3ms sinusoidal, T<sub>j</sub>=150°C \*5 T<sub>c</sub>=100°C, T<sub>j</sub>=150°C, Duty cycle=10%\*6 T<sub>c</sub>=25°C \*7 Per leg / Both legs● Electrical characteristics (T<sub>j</sub> = 25°C) (Per leg)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
DC blocking voltage	V <sub>DC</sub>	I <sub>R</sub> =0.1mA	1200	-	-	V
Forward voltage	V <sub>F</sub>	I <sub>F</sub> =5A, T <sub>j</sub> =25°C	-	1.4	1.6	V
		I <sub>F</sub> =5A, T <sub>j</sub> =150°C	-	1.8	-	V
		I <sub>F</sub> =5A, T <sub>j</sub> =175°C	-	1.9	-	V
Reverse current	I <sub>R</sub>	V <sub>R</sub> =1200V, T <sub>j</sub> =25°C	-	5	100	μA
		V <sub>R</sub> =1200V, T <sub>j</sub> =150°C	-	40	-	μA
		V <sub>R</sub> =1200V, T <sub>j</sub> =175°C	-	65	-	μA
Total capacitance	C	V <sub>R</sub> =1V, f=1MHz	-	270	-	pF
		V <sub>R</sub> =800V, f=1MHz	-	21	-	pF
Total capacitive charge	Q <sub>c</sub>	V <sub>R</sub> =800V, di/dt=500A/μs	-	17	-	nC
Switching time	t <sub>c</sub>	V <sub>R</sub> =800V, di/dt=500A/μs	-	15	-	ns

## ● Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance	R <sub>th(j-c)</sub>	Per Leg	-	1.5	1.8	°C/W
		Both Legs	-	0.75	0.86	°C/W

# RATINGS AND CHARACTERISTIC CURVES

## ● Electrical characteristic curves

Fig.1  $V_F$  -  $I_F$  Characteristics (Per leg)

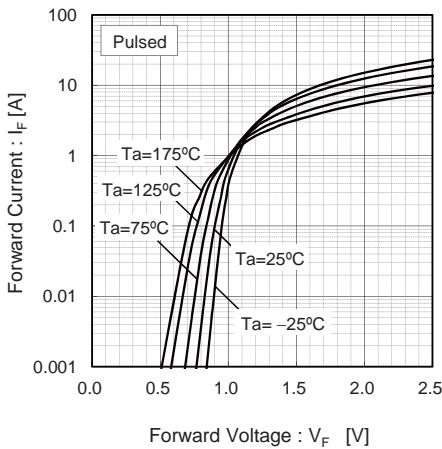


Fig.2  $V_F$  -  $I_F$  Characteristics (Per leg)

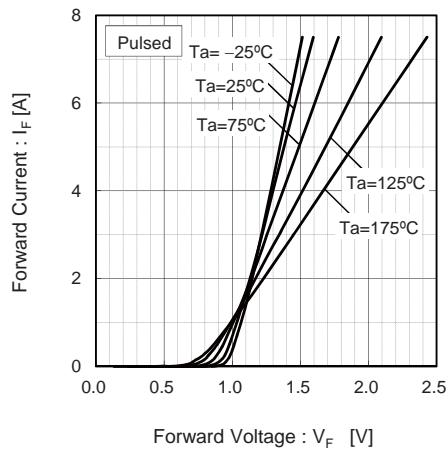


Fig.3  $V_R$  -  $I_R$  Characteristics (Per leg)

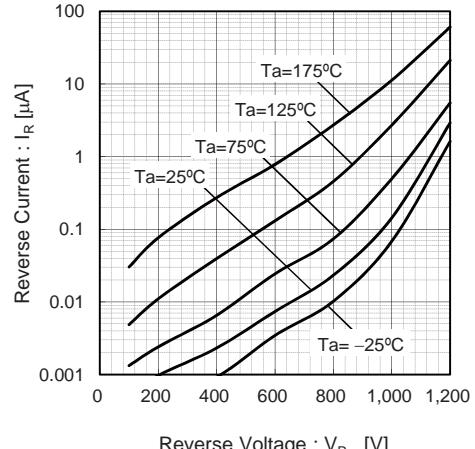


Fig.4  $V_R$ - $C_t$  Characteristics (Per leg)

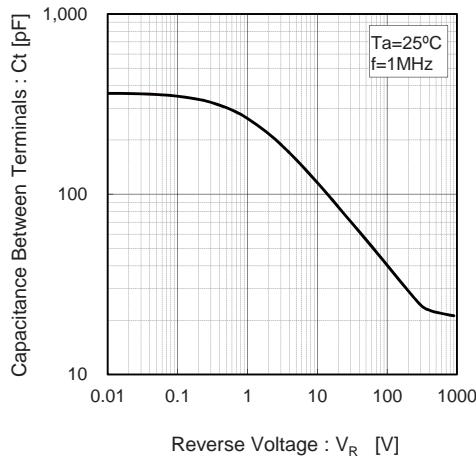


Fig.5 Thermal Resistance vs. Pulse Width (Per leg)

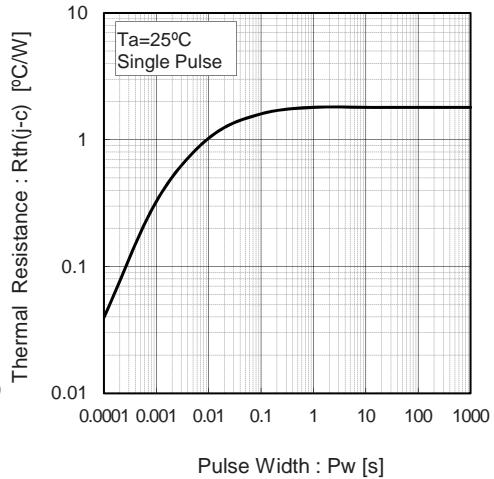


Fig.6 Power Dissipation (Per leg)

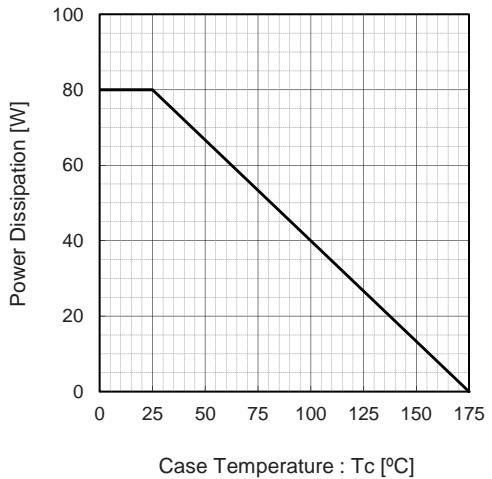


Fig.7  $I_p$ - $T_c$  Derating Curve (Per leg)

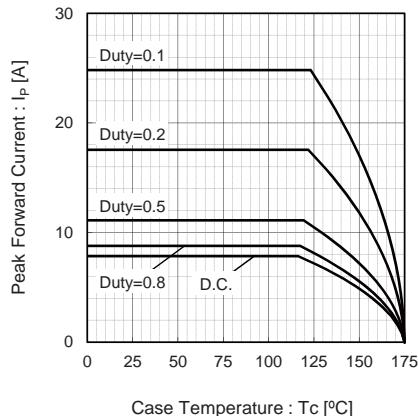


Fig.8  $I_o$ - $P_f$  Characteristics (Per leg)

